

#### SLPS257A - MARCH 2010 - REVISED SEPTEMBER 2010

# 30V N-Channel NexFET<sup>™</sup> Power MOSFET

Check for Samples: CSD17311Q5

## **FEATURES**

- **Optimized for 5V Gate Drive**
- Ultra Low Q<sub>a</sub> and Q<sub>ad</sub>
- Low Thermal Resistance
- **Avalanche Rated**
- **Pb Free Terminal Plating**
- **RoHS Compliant**
- **Halogen Free**
- SON 5-mm × 6-mm Plastic Package

#### **APPLICATIONS**

- **Notebook Point-of-Load**
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems

# DESCRIPTION

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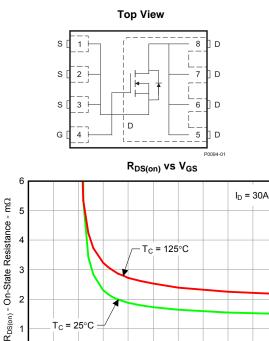
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T<sub>C</sub> = 25°C

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The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications and optimized for 5V gate drive applications.



T<sub>C</sub> = 125°C

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V<sub>GS</sub> - Gate-to-Source Voltage - V

7 8 9 10

# **PRODUCT SUMMARY**

V <sub>DS</sub>	Drain to Source Voltage	30	V	
Qg	Gate Charge Total (4.5V) 24			
Q <sub>gd</sub>	Gate Charge Gate to Drain 5.2			
		$V_{GS} = 3V$	2.3	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	V <sub>GS</sub> = 4.5V 1.8		mΩ
		V <sub>GS</sub> = 8V 1.6		mΩ
V <sub>GS(th)</sub>	Threshold Voltage	1.2		V

#### **ORDERING INFORMATION**

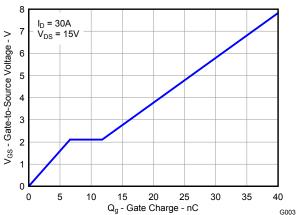
Device	Package	Media	Qty	Ship
CSD17311Q5	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

#### **ABSOLUTE MAXIMUM RATINGS**

$T_A = 2$	5°C unless otherwise stated	VALUE	UNIT
V <sub>DS</sub>	Drain to Source Voltage	30	V
$V_{GS}$	Gate to Source Voltage	+10 /8	V
	Continuous Drain Current, $T_C = 25^{\circ}C$	100	А
ID	Continuous Drain Current <sup>(1)</sup>	32	А
I <sub>DM</sub>	Pulsed Drain Current, $T_A = 25^{\circ}C^{(2)}$	200	А
PD	Power Dissipation <sup>(1)</sup>	3.2	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, Single Pulse $I_D = 113A$ , L = 0.1mH, $R_G = 25\Omega$	638	mJ

(1) Typical  $R_{\theta JA}$  = 40°C/W when mounted on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.

(2) Pulse duration ≤300µs, duty cycle ≤2%



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G006

# CSD17311Q5

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XAS STRUMENTS

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

# **ELECTRICAL CHARACTERISTICS**

$(T_A = 25^{\circ})$	°C unless otherwise stated)				
	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
Static Cl	haracteristics				
$BV_{DSS}$	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250 \mu A$	30		V
I <sub>DSS</sub>	Drain to Source Leakage Current	$V_{GS} = 0V, V_{DS} = 24V$		1	μA
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10/-8V$		100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.9 1.2	1.6	V
		$V_{GS} = 3V, I_D = 30A$	2.3	3.1	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 30A$	1.8	2.3	mΩ
		$V_{GS} = 8V, I_D = 30A$	1.6	2	mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 30A	200		S
Dynamic	Characteristics				
C <sub>iss</sub>	Input Capacitance		3290	4280	pF
C <sub>oss</sub>	Output Capacitance	$V_{GS} = 0V, V_{DS} = 15V,$ f = 1MHz	1740	2260	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		85	110	pF
R <sub>G</sub>	Series Gate Resistance		1.2	2.4	Ω
Qg	Gate Charge Total (4.5V)		24	31	nC
Q <sub>gd</sub>	Gate Charge Gate to Drain	V <sub>DS</sub> = 15V,	5.2		nC
Q <sub>gs</sub>	Gate Charge Gate to Source	$I_{DS} = 30A$	6.6		nC
Q <sub>g(th)</sub>	Gate Charge at Vth		3.9		nC
Q <sub>oss</sub>	Output Charge	$V_{DS} = 14.8V, V_{GS} = 0V$	47		nC
t <sub>d(on)</sub>	Turn On Delay Time		12		ns
tr	Rise Time	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 4.5V,	18		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$I_{DS} = 30A, R_G = 2\Omega$	33		ns
t <sub>f</sub>	Fall Time		12		ns
Diode C	haracteristics	· · ·	L		
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 30A, V <sub>GS</sub> = 0V	0.85	1	V
Q <sub>rr</sub>	Reverse Recovery Charge	V <sub>DD</sub> = 14.8V, I <sub>F</sub> = 30A,	74		nC
t <sub>rr</sub>	Reverse Recovery Time	di/dt = 300A/µs	39		ns

## THERMAL CHARACTERISTICS

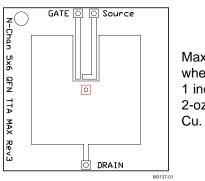
$(T_A = 25^{\circ}C \text{ unless otherwise stated})$								
	PARAMETER	MIN	TYP	MAX	UNIT			
$R_{\thetaJC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			1	°C/W			
$R_{\thetaJA}$	Thermal Resistance Junction to Ambient <sup>(1)(2)</sup>			49	°C/W			

 $R_{ ext{BJC}}$  is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB.  $R_{ ext{BJC}}$  is specified by design, whereas  $R_{ ext{BJA}}$  is determined by the user's board design. Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu. (1)

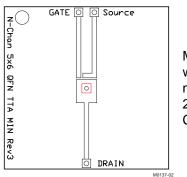
(2)







Max  $R_{\theta JA} = 49^{\circ}C/W$ when mounted on 1 inch<sup>2</sup> (6.45 cm<sup>2</sup>) of 2-oz. (0.071-mm thick) Cu.



Max  $R_{\theta,JA} = 120^{\circ}C/W$ when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

#### **TYPICAL MOSFET CHARACTERISTICS**

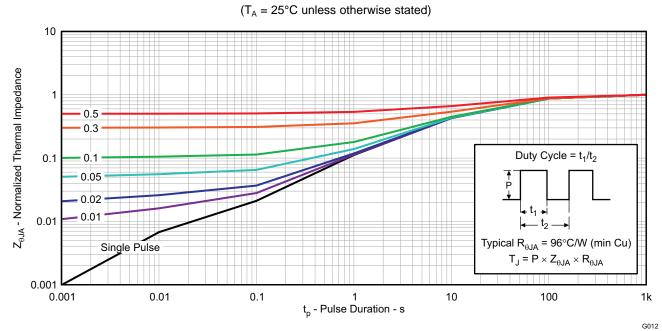


Figure 1. Transient Thermal Impedance

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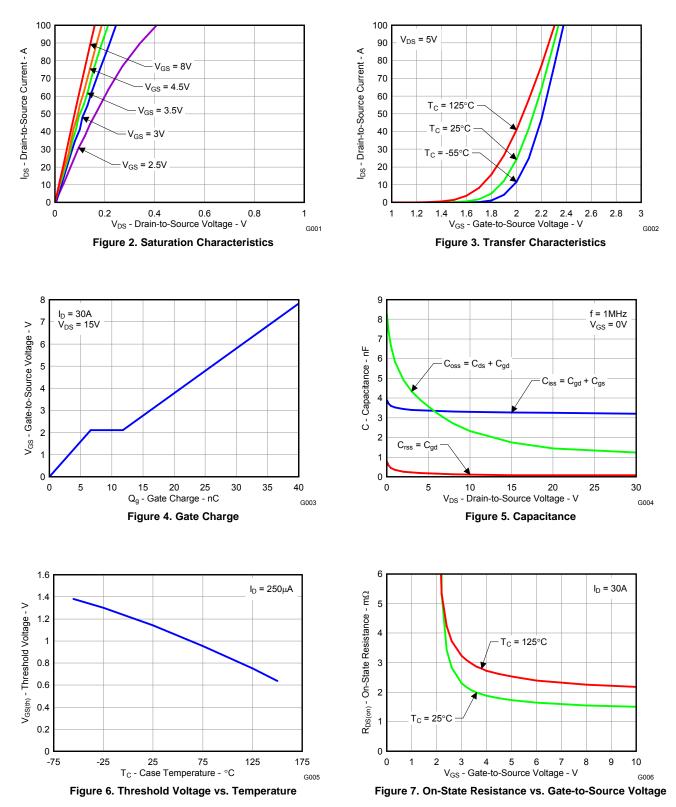
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**ISTRUMENTS** 

**EXAS** 

#### **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 





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#### **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

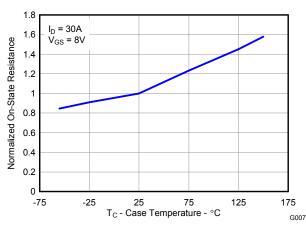
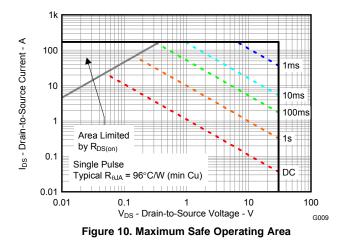


Figure 8. Normalized On-State Resistance vs. Temperature



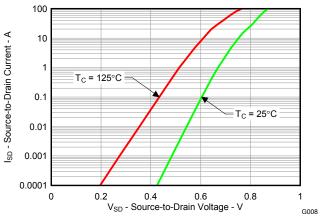


Figure 9. Typical Diode Forward Voltage

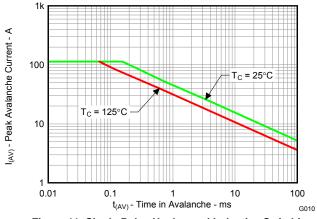


Figure 11. Single Pulse Unclamped Inductive Switching

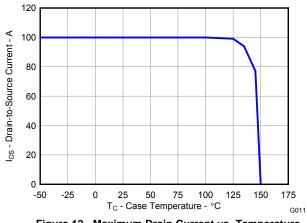


Figure 12. Maximum Drain Current vs. Temperature

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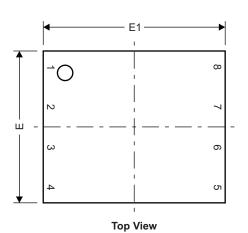
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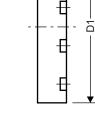
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### **MECHANICAL DATA**

c1

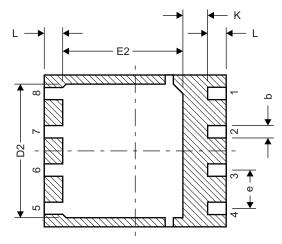
## **Q5 Package Dimensions**



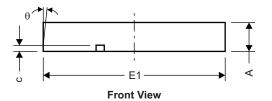


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Side View



**Bottom View** 



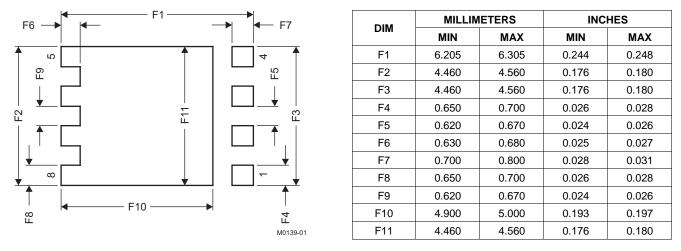
M0140-01

DIM	MILLIM	ETERS	INCHES			
DIW	MIN	MAX	MIN	MAX		
A	0.950	1.050	0.037	0.039		
b	0.360	0.460	0.014	0.018		
С	0.150	0.250	0.006	0.010		
c1	0.150	0.250	0.006	0.010		
D1	4.900	5.100	0.193	0.201		
D2	4.320	4.520	0.170	0.178		
E	4.900	5.100	0.193	0.201		
E1	5.900	6.100	0.232	0.240		
E2	3.920	4.12	0.154	0.162		
е	1.27	TYP	0.0	)50		
К	0.760		0.030			
L	0.510	0.710	0.020	0.028		
θ	0.00					



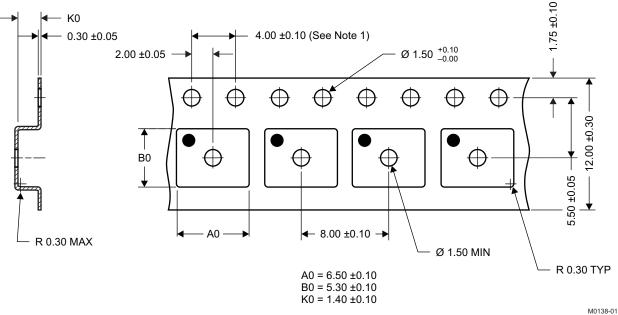
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#### Recommended PCB Pattern



For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

# Q5 Tape and Reel Information



Notes: 1. 10-sprocket hole-pitch cumulative tolerance ±0.2

2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm

- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm, unless otherwise specified.
- 5. Thickness: 0.30 ±0.05mm
- 6. MSL1 260°C (IR and convection) PbF reflow compatible

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## **REVISION HISTORY**

Cł	nanges from Original (March 2010) to Revision A	Page
•	Deleted the Package Marking Information section	7



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7-Jan-2016

## PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD17311Q5	ACTIVE	VSON-CLIP	DQH	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD17311	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(<sup>6)</sup> Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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# PACKAGE OPTION ADDENDUM

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